RESEARCH ARTICLE

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Optoelectronic and transport properties of Rb/Cs₂TeI₆ defective perovskites for green energy applications

| Malak Azmat Ali ¹ Ali | H. Reshak ^{2,3,4} | Ghulam Murtaza ⁵ 💿 🛛 | |
|------------------------------------|----------------------------|----------------------------------|------------------------|
| Murefahmana AL-Anazy ⁶ | Hind Althib ^{7,8} | Tahani H. Flemban ^{7,8} | Jiri Bila ³ |

¹Department of Physics, Government Post Graduate Jahanzeb College, Saidu Sharif, Pakistan

²Physics Department, College of Science, University of Basrah, Basrah, Iraq

³Department of Instrumentation and Control Engineering, Faculty of Mechanical Engineering, CTU in Prague, Prague, Czech Republic

⁴Center of Excellence Geopolymer and Green Technology, School of Material Engineering, University Malaysia Perlis, Kangar, Malaysia

⁵Materials Modeling Lab, Department of Physics, Islamia College Peshawar, Peshawar, Pakistan

⁶Department of Chemistry, College of Science, Princess Nourah Bint Abdulrahman University, Riyadh, Saudi Arabia

⁷Basic and Applied Scientific Research Center, Imam Abdulrahman Bin Faisal University, Dammam, Saudi Arabia

⁸Department of Physics, College of Science, Imam Abdulrahman Bin Faisal University, Dammam, Saudi Arabia

Correspondence

Ali H. Reshak, Physics Department, College of Science, University of Basrah, Basrah, Iraq. Email: maalidph@yahoo.co.uk

Summary

Lead content in perovskite solar cells and other applications is toxic for human health and environment. Therefore, the search alternate materials are required of present era. In this article, we presented physical properties of Rb/Cs_2TeI_6 defective perovskites for possible solar cell and thermoelectric applications. These compounds were found to be stable in perovskite structure. The band gaps were calculated in close contact to experiments. The optical properties were computed in term of dielectric function, refractive index and optical conductivity. These properties explored suitability of Rb/Cs_2TeI_6 perovskites for solar cell applications. Also, the high figure of merit (0.687 for Rb_2TeI_6 and 0.682 for Cs_2TeI_6 at 1000 K) confirmed position of these compounds in family of efficient thermoelectric materials.

K E Y W O R D S

defective perovskites, figure of merit, optical conductivity, solar cell applications, thermoelectric materials

1 | INTRODUCTION

Despite maximum reported efficiency,¹ the lead halide perovskites are toxic to be used in solar cells and thermoelectric generators because the lead contents of these compounds may cause symptoms ranging from the loss of function of neurons to death depending upon the amount and exposure time.² Average exposure levels in children leaving near the plants of lead solar cells and battery in developing countries are four times of the level established by the World Health Organization.³ Therefore, it is highly recommended to replace the solar cells contents by environmentally friendly materials.

The half of B site cation removed in ABX₃ perovskites may be alternative of lead halide perovskites. These materials are represented by A_2BX_6 and termed as defective perovskites. A number of researchers carried investigations on materials in A_2BX_6 group and reported them as excellent absorber to be used in solar cell applications.⁴⁻¹² Also materials of this group have been reported with excellent thermoelectric properties.⁴⁻⁷ Among A_2BX_6 defective perovskites, Rb/Cs₂TeI₆ compounds have not been studies at experimental or theoretical level for solar cells and thermoelectric applications. Abriel¹³ prepared Rb₂TeI₆ and reported it with cubic A_2BX_6 at 340 K. Sidey et al¹⁴ reported lattice constant of Cs₂TeI₆ as 11.700 Å from his experiment. Peresh et al¹⁵ also reported the cubic structure of Rb₂TeI₆ along with Cs₂TeI₆. They relations were used to calculate tolerance factor (*t*) (Equation (1)),²⁴ enthalpy of formation (ΔH) (Equation (2)),²⁵ and lattice parameters (Equation (3))²⁶

$$t = \frac{r_{Te} + r_{Rb/Cs}}{\sqrt{2}(r_{Cl} + r_{Te})}$$
(1)

$$\Delta H = E(Rb_2/Cs_2TeBr_6) - 2(E_{Cs/Rb}) - (E_{Te}) - 6(E_I) \quad (2)$$

$$E(V) = E_o + \frac{9V_o B}{16} \left[\left\{ 6 - 4 \left(\frac{V_o}{V} \right)^{\frac{2}{3}} \right\} \left\{ \left(\frac{V_o}{V} \right)^{\frac{2}{3}} - 1 \right\}^2 + \left\{ \left(\frac{V_o}{V} \right)^{\frac{2}{3}} - 1 \right\}^3 B^{/} \right]$$
(3)

reported the band gap of Rb_2TeI_6 as 1.4 eV and as Cs_2TeI_6 1.5 eV from their experiment. Brik and Kityk¹⁶ calculated lattice constant for Cs_2TeI_6 from their developed analytical technique. Rahim et al¹⁷ also calculated the lattice constant for Cs_2TeI_6 at analytical level. Up till now, the optical and thermoelectric properties neither reported experimentally nor theoretically while electronic properties were not studied theoretically. Therefore, it will be very interesting to investigate the optical and thermoelectric properties further.

In the present article, we reported the density functional theory based results of lattice parameters, optical and thermoelectric spectra, and electronic properties in term of band structure and density of states for Rb/Cs_2TeI_6 defective perovskites. The new results on these compounds can cover the lack of theoretical data and motivate experimentalist to investigate these further.

2 | METHOD OF CALCULATIONS

Full potential linearized augmented plane wave method written in FORTRAN language in Wien2k computational code¹⁸ was utilized in present study. This method is taught to be excellent in term of calculation of structural, electronic, and optical properties.^{19,20} Also maximum number of exchange correlation potential has been added to this method were integrated in Wien2k code. Within these potentials, we have applied Wu-Cohen²¹ and Engle-Vosko²² modified generalized gradient approximation (WC-GGA and EV-GGA) for the calculations of the article. WC-GGA was used for structural minimization and optimization while EV-GGA use taken in account for computation of electronic and optical properties. The scf file of EV-GGA was utilized in BoltzTraP code²³ for calculation of thermoelectric parameters. Some of analytical

In Equation (1), r represents the radius of the respective atom in subscript, in Equation (2) each terms is the energy of unit cell or constituent atom in subscript while in Equation (3), E_o , V_o , B, B', and V are ground state energy, volume, bulk modulus, variation in bulk modulus with respect to pressure and variable volume, respectively.

3 | RESULTS AND DISCUSSION

3.1 | Structural properties

Rb/Cs₂TeI₆ compounds have K₂PtCl₆ type structure with Fm-3 m (#225) space group. Where, Rb/Cs atoms occupy (0.25, 0.25, 0.25) position, Te atom substitutes (0, 0, 0) position, and I atoms take (X, 0, 0). X is anion displacement parameters which is calculated by internal minimization technique and given in Table 1. The reliability of Rb/Cs₂TeI₆ compounds within cubic defective perovskite family was checked via calculating their tolerance factors (*t*) by relation given in Equation (1) by taken the ionic radii of constituent atoms from Reference 27. The

TABLE 1 The elemental energies of Cs/Rb, Te, and I in bulk with ground stated energy and enthalpy of formation of $E(Rb_2/Cs_2TeI_6)$

| Parameter | Rb ₂ TeBr ₆ | Cs ₂ TeBr ₆ |
|---------------------|-----------------------------------|-----------------------------------|
| $E_{Cs/Rb}$ | -81 080.61 | -211 873.32 |
| E_{Te} | -184 853.11 | -184 853.11 |
| E_I | -193 616.52 | -193 616.52 |
| $E(Rb_2/Cs_2TeI_6)$ | -1 508 727.69 | -1 770 312.527 |
| ΔH | -14.24 | -13.66 |
| | | |

| TABLE 2 Present calculated lattice constant (a_{\circ}) , volume (V_{\circ}) , Bulk modulus (B) , and its derivative with respect to pressure (B') , and anion displacement parameter (X) for Rb/Cs ₂ TeI ₆ with available experimental (Exp.) and theoretical result | Compound | <i>a</i> _° (Å) | <i>V</i> _• (Å ³) | B (GPa) | B ⁄ | X | Remarks |
|--|----------------------------------|---------------------------|---|---------|------------|--------|--|
| | Rb ₂ TeI ₆ | 11.5888 | 1554.44 | 20.58 | 5 | 0.2527 | Present |
| | Cs ₂ TeI ₆ | 11.67 11.6423 | 1576.08 | 20.46 | 5 | 0.2522 | Exp. ¹³ Present |
| | | 11.70 | | | | | Exp. ¹⁴ |
| | | 11.74 11.7 | | | | | Theo. ¹⁶ Theo. ¹⁷ |

calculate *t* for Rb₂TeI₆ and Cs₂TeI₆ are 0.91 and 0.87, respectively. Therefore, Rb/Cs₂TeI₆ compounds are perovskites by condition 0.825 < t < 1.059.²³

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A compound with negative enthalpy of formation (ΔH) is termed as thermodynamically stable. To examine the stability of Rb/Cs₂TeI₆ compounds on basis of thermodynamics we have calculated the ΔH by fitting the data (ground state energies of Rb/Cs₂TeI₆ compounds and their constituent atoms) of Table 2 in Equation (2). The computed values are negative as seen from the table. These values guarantee the thermodynamic stability of the studied compounds.

In computational condense matter physics, Birch-Murnaghan's equation of state (Equation (3)) is used for calculation of structural parameters. Therefore, we have placed the data of volume optimization process in Equation (3) in order to get plots as in Figure 1. For which, we have selected the V_{\circ} , B, B', and E_{\circ} as constants. These constants (Table 1) are the computed structural parameters. The $B(V_{\circ})$ of Rb₂TeI₆ is larger (smaller) than Cs₂TeI₆ because of comparatively smaller size of Rb than Cs. The lattice constant (a_{\circ}) was calculated from respective volume ($a_{\circ} = V^{1/3}$) and were found in excellent agreement with available result in experiment as clear from Table 1. The a_{\circ} of Cs₂TeI₆ is larger than Rb₂TeI₆ because of larger volume.

-1508727. Rb₂Tel₆ -1770311.6 Cs_aTel_a -1508727.3 -1770311.8 🚡 Energy of Rb₂Tel₆ (eV) Cs₂Tel₆ (1508727 1770312.0 -1770312.2 Jo 1508727.5 -1508727.6 -1770312.4 -1508727.3 -1770312.6 1450 1500 1550 1600 1650 1700 1750 1800 1850 1400 Volume (Å³)

FIGURE 1 Volume optimization plot for Rb/Cs₂TeI₆

3.2 | Electronic properties

The optical fitness of a material in solar cells and other related applications depend on its electronic properties. Therefore, we have calculated the electronic properties of Rb/Cs₂TeI₆ compounds via WC-GGA and EV-GGA in term of electronic band structure and density of states (DOS). Figure 2 contains only the band structures and DOS through EV-GGA because of similar response as by WC-GGA. The calculated band gaps $(W \rightarrow \Gamma)$ through WC-GGA underestimates than experimental values while the values of EV-GGA little overestimates. However, the values of EV-GGA are in close resemblance with experimental values as clear from Table 3. We will use these values for calculation of optical and thermoelectric properties. The valence band maximum of both Rb/Cs₂TeI₆ compounds is flat. Hence, it is expected that both the compounds have excellent thermoelectric properties. In addition, optical properties are also expected to be better for solar cells and other optoelectronic properties. Because the DOS plots elaborate transition from I-5p states in valence band to Te-5p states in conduction band in case of both Rb/Cs₂TeI₆ perovskites.

3.3 | Optical properties

The optical fitness of a material to solar cell and optoelectronic applications can be deduced from important parameters such as real and imaginary parts of dielectric function (($\mathcal{E}_1(\lambda)$ and $\mathcal{E}_2(\lambda)$)), optical conductivity ($\sigma(\lambda)$) and refractive index ($n(\lambda)$). All these optical parameters were calculated as function of incident photon wavelength as depicted in Figures 3 and 4. Where, Rb/Cs₂TeI₆ compounds response to incident electromagnetic radiations in same way. As discussed above, that transition of charges take place between Te-5*p* and I-5*p* states when incident light is absorbed by Rb/Cs₂TeI₆ compounds. These states are speared in long range of conduction and valence bands. Therefore, despite low fundamental band gaps, Rb/Cs₂TeI₆ looks best for solar cell applications. To check this possibility, we calculated $\mathcal{E}_1(\lambda)$, $\mathcal{E}_2(\lambda)$, $\sigma(\lambda)$, and

3



FIGURE 2 The calculated electronic band structure with density of stated for, A, Rb_2TeBr_6 and, B, Cs_2TeBr_6 defective perovskites via EV-GGA [Colour figure can be viewed at wileyonlinelibrary.com]

TABLE 3Calculated band gaps through WC-GGA and EV-GGA along with experimental values

| Compound | Present (eV) | | Exp. (eV) |
|----------------------------------|--------------|--------|-------------------|
| | WC-GGA | EV-GGA | |
| Rb ₂ TeI ₆ | 1.321 | 1.482 | 1.4^{15} |
| Cs ₂ TeI ₆ | 1.344 | 1.521 | 1.5 ¹⁵ |

 $n(\lambda)$ in wavelength range of 250-750 nm as visible range is 400-700 nm.

Figure 3A elaborates the dispersion behavior of Rb/Cs₂TeI₆ in term of $\mathcal{E}_I(\lambda)$. At 250 nm, both the studied compounds have nearly zero dispersion. This value gets increase when wavelength of incident light increases. The maximum recorded value for Rb₂TeI₆ is 5.73 at 472 nm and for Cs₂TeI₆ is 5.69 at 496.7 nm wavelength. The values of $\mathcal{E}_I(\lambda)$ for both defective perovskites decrease linearly as the wavelength value increases and reaches to zero beyond red light.

 $\mathcal{E}_2(\lambda)$ is used to describe the absorption ability of a materials when photons fall on it. The computed spectrum of $\mathcal{E}_2(\lambda)$ is shown in Figure 3B for Rb/Cs₂TeI₆

defective double perovskites. At 250 nm, both compounds have the value of $\mathcal{E}_2(\lambda)$ as 1. Beyond 250 nm, it increases and reaches to maximum value of 6.69 (at 443.7 nm) and 5.35 (at 463.1 nm) for Rb₂TeI₆ and Cs₂TeI₆, respectively. At 443.7 and 463.1 nm, minima peaks of $\mathcal{E}_I(\lambda)$ for Rb₂TeI₆ and Cs₂TeI₆, respectively, occur. It means that Rb₂TeI₆ has maximum absorption and less dispersion ability for violet light (380-450 nm) and Cs₂TeI₆ for blue light (450-495 nm). Overall, the enough good absorption in visible range makes both the compounds effective for solar cell applications.

The optical conductivity $(\sigma(\lambda))$ in Figure 3C follow the same trend in $\mathcal{E}_2(\lambda)$ in Figure 3B because absorption of light enables the charge carrier for conductance after getting transition of from valence to conduction band. The maximum values of $\sigma(\lambda)$ of 6431.9 (Ω^{-1} cm⁻¹) for Rb₂TeI₆ and 4932. 5 (Ω^{-1} cm⁻¹) for Cs₂TeI₆ take place at wavelengths for which maximum of $\mathcal{E}_2(\lambda)$ was observed. In entire taken range of wavelengths, the minimum values of $\sigma(\lambda)$ for both Rb/Cs₂TeI₆ compounds were observed for red light as clear from Figure 3B.

The refractive index $n(\lambda)$ measured for Rb/Cs₂TeI₆ perovskites is shown in Figure 3D. In regions 250-340 nm



FIGURE 3 Calculated real and imaginary parts of dielectric function (($\mathcal{E}_1(\lambda)$ and $\mathcal{E}_2(\lambda)$)), optical conductivity ($\sigma(\lambda)$), and refractive index ($n(\lambda)$) thermoelectric properties

and 660-750 nm, the $n(\lambda)$ has values lower than unity. In these regions, the phase velocity of the electromagnetic radiations exceeds the velocity of light ($v_p > c$) which looks to be nonphysical. In region 341-559 nm, the values of n greater than 1 reflects the transparent behavior of both the compounds. The maximum reported values of n (λ) are 2.539 (at $\lambda = 466.8$ nm) for Cs₂TeI₆ and 2.477 (at $\lambda = 490.4$ nm) for Rb₂TeI₆.

3.4 | Thermoelectric properties

The Rb/Cs₂TeI₆ compounds were investigated for thermoelectric power generation in term of, total thermal conductivity (κ) along with its electronic (κ_e) and lattice parts (κ_L), electronic conductivity (σ/τ), Seebeck coefficient (*S*), power factor (*PF*/ τ), and figure of merit (*ZT*) in temperature range of 100-1000 K and summarized in Figures 4 to 6. All these parameters except κ_L were calculated through BoltzTraP code while the calculation of κ_L was carried out using Slack equation.²⁸ Figure 4A-C depicts the computed κ_e , κ_L , and κ , respectively. κ_e is measure of electronic part in heat transfer. Its value increases with increase in temperature for semiconductors. Figure 4A is evidence of this statement. Where, κ_e increases from 0.147×10^{14} to 8.19×10^{14} W/mKs for Rb₂TeI₆ and 0.148×10^{14} to 7.91×10^{14} W/mKs for Cs₂TeI₆. Figure 4B shows phonon contribution (lattice thermal conductivity, κ_L) to heat transfer calculated via Slack equation.²⁸

$$\kappa_L = A \frac{\Theta_D^3 \mathbf{V}^{\frac{1}{3}} \mathbf{M}_{\text{avg}}}{\gamma^2 n^{\frac{2}{3}} T \tau} \tag{4}$$

In Equation (4), γ is the Grüneisen parameter, *A* is γ dependent coefficient (~3.1 × 10⁻⁶ for κ_L in W/mKs),²⁹ *V* is the volume (in unit of Å³) per primitive unit cell, *M* is the average atomic mass (in unit of amu) of all the atoms, τ is relaxation time (10⁻¹⁴ seconds), *T* is the temperature in *K*, Θ_D is Debye temperature in *K*, and *n* is the total number of atoms in primitive unit cell. Θ_D (153.35)



FIGURE 4 Calculated, A, electronic (κ_e), B, thermal (κ_L), and, C, total (κ) thermal conductivities of Rb/Cs₂TeI₆ compounds [Colour figure can be viewed at wileyonlinelibrary.com]



FIGURE 5 The calculated, A, electronic conductivity (σ/τ), B, Seebeck coefficient (*S*), and, C, power factor (*PF*/ τ) and for Rb/Cs2TeI6 defective perovskites [Colour figure can be viewed at wileyonlinelibrary.com]

for Rb₂TeI₆ and 148.01 for Cs₂TeI₆) and γ (2.35 for both Rb/Cs₂TeI₆ compounds) are calculated through Quasiharmonic Debye approximation.³⁰ Figure 4B specifies that κ_L decreases with rise in temperature. When temperature rises, the inter-atomic lattice chain becomes weaker. This causes a decrease in phonon group velocity and hence in κ_L . The total thermal conductivity ($\kappa = \kappa_e + \kappa_L$) is depicted in Figure 4C. Both the Rb/Cs₂TeI₆ compounds show



FIGURE 6 The computed figure of merits (*ZT*) for Rb/Cs2TeI6 defective perovskites [Colour figure can be viewed at wileyonlinelibrary.com]

similar behavior. Up to room temperature, κ decreases and then increases with further rise in temperature. This is justified by respective values of κ_e and κ_L .

Figure 5A shows the calculated relaxation time dependent electronic conductivity (σ/τ). Where, σ/τ is nearly linear relationship with temperature. This type behavior is common for semiconductor type materials.³¹ Because, an increase in temperature causes decrease in resistance in a semiconductor, as result the charges conductivity rises. The maximum values of σ/τ were noted at 1000 K as 1.92×10^{19} (Ω ms)⁻¹ for Rb₂TeI₆ and 1.83×10^{19} (Ω ms)⁻¹ for Cs₂TeI₆.

The *S* in Figure 5B shows the same behavior for Rb/Cs_2TeI_6 compounds throughout entire temperature range. Initially, its values increase up to 500 K and then decrease linearly with rise in temperature. The maximum value was calculated for 192.01 V/mK for Rb_2TeI_6 and 189.24 V/mK for Cs_2TeI_6 at 500 K. In addition, the positive values of *S* in whole temperature range specify the studied compounds as p-type semiconductors.

Power factor $PF/\tau = \sigma S^2/\tau^{32}$ varies with temperature change as shown in Figure 5C. The values of PF/τ for both perovskites increase linearly up to 500 K and then increase is comparatively smooth. Maximum values of PF/τ for reference in future works are 59.42×10^{10} and 56.76×10^{10} Wm/K²s, respectively, for Rb₂TeI₆ and Cs₂TeI₆. The increase of PF/τ with rise in temperature makes Rb/Cs₂TeI₆ compounds as thermoelectric potential materials.

A dimensionless quantitative, figure of merit (*ZT*) describes the efficiency of material to convert heat in electrical energy. The *ZT* for Rb/Cs_2TeI_6 perovskites as function of temperature is shown in Figure 6. The

maximum values of ZT are reported as 0.687 for Rb₂TeI₆ and 0.682 for Cs₂TeI₆ at 1000 K. In wide range conditions, the *p*-type Rb/Cs₂TeI₆ perovskites with good ZT values as novel materials for efficient thermoelectric devices.

4 | CONCLUSIONS

The density functional theory employed in wien2k computational code was used to investigate structural, electronic, optical and thermoelectric properties of Rb/Cs₂TeI₆ defective perovskites. The bulk modulus and enthalpy of formation provide as reference data. In addition, the negative values of enthalpy of formation confirmed the thermodynamic stability of both the compounds. The band gaps calculated through EV-GGA were found in close agreement with experimental values. From density of states calculations, it was explored that band gap is attributed by Te-5p states in conduction band and I-5p states in valence band. The excellent absorption and conductance in visible region of electromagnetic spectrum ensured the commercial use of lead free Rb/Cs₂TeI₆ compounds in solar cell applications. Also, the calculated reasonable values of electronic conductivity, Seebeck coefficient, power factor, and figure of merit make p-type Rb/Cs₂TeI₆ perovskites favorable for thermoelectric power generation.

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DATA AVAILABILITY STATEMENT

Data sharing not applicable to this article as no datasets were generated or analyzed during the current study (the article describes entirely theoretical research).

ORCID

Malak Azmat Ali https://orcid.org/0000-0002-6290-0317

Ali H. Reshak https://orcid.org/0000-0001-9426-8363 *Ghulam Murtaza* https://orcid.org/0000-0001-5520-2265

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